



NHD-C0216AZ-FSW-GBW

COG (Chip-on-Glass) Liquid Crystal Display Module

NHD- Newhaven Display

CO216- COG, 2 Lines x 16 Characters

AZ- Model

F- Transflective

SW- Side White LED Backlight

G- STN- Gray

B- 6:00 Optimal View

W- Wide Temp

RoHS Compliant

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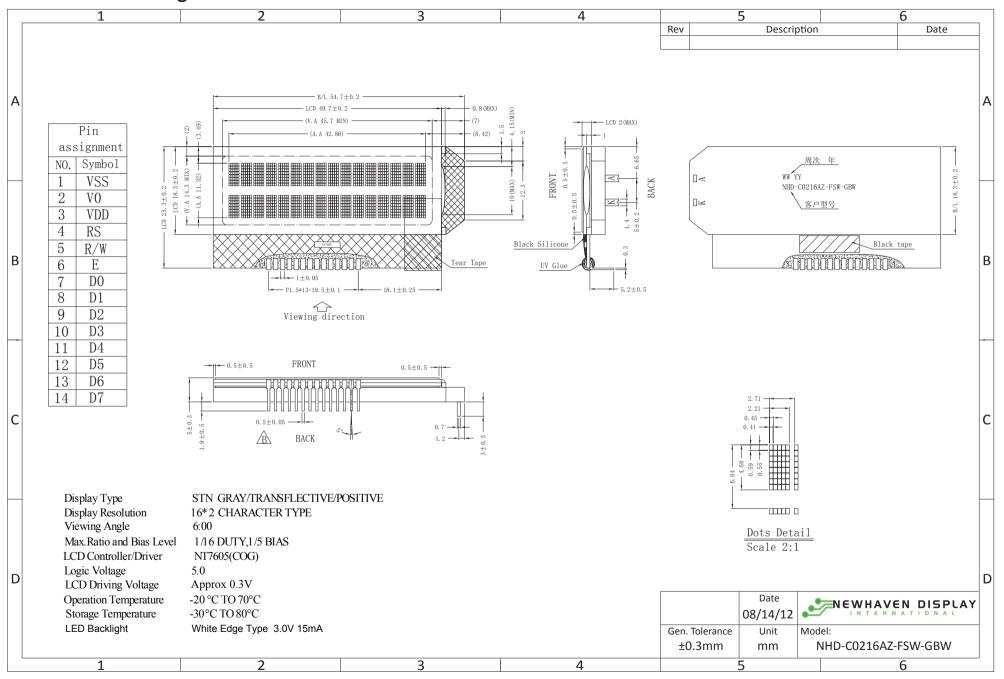
Document Revision History

Revision	Date	Description	Changed by
0	2/12/2007	Initial Release	
1	2/19/2009	User guide reformat	BE
2	10/9/2009	Updated Electrical Characteristics	MC
3	10/15/2009	Updated Block Diagram	MC
4	6/2/2011	Timing characteristics updated	AK
5	8/14/2012	Mechanical drawing updated	AK
6	9/16/2014	Electrical Characteristics updated	ML

Functions and Features

- 2 lines x 16 characters
- Built-in NT7605 controller
- 5x8 dots with cursor
- +5V power supply
- 1/16 duty, 1/5 bias
- RoHS Compliant

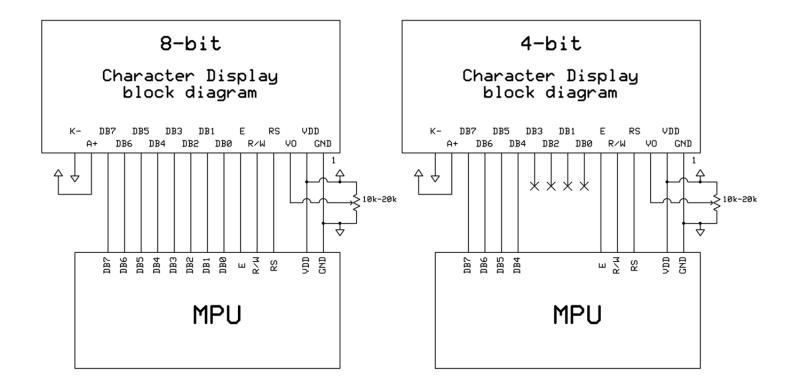
Mechanical Drawing



Pin Description and Wiring Diagram

Pin No.	Symbol	External	Function Description
		Connection	
1	Vss	Power Supply	Ground
2	Vo	Adj. Power supply	Power supply for contrast (approx. 0.3V)
3	VDD	Power Supply	Supply voltage for logic (5.0V)
4	Rs	MPU	Register select signal. RS=0: Command, RS=1: Data
5	R/W	MPU	Read/Write select signal, R/W=1: Read R/W=0: Write
6	E		Operation enable signal. Falling edge triggered.
7-10	DB0-DB3		Four low order bi-directional three state data bus lines. These four
		MPU	are not used during 4-bit operation.
11-14	DB4-DB7		Four high order bi-directional three state data bus lines.
15	Α		Power supply for LED Backlight (3.0V)
		power supply	
16	K	pome. Supply	Ground for Backlight

Recommended LCD connector: 1.5 mm pitch, 14 pins Soldered to PCB **Backlight connector:** A and K pins **Mates with**: Solder to wires or PCB



Electrical Characteristics

Item	Symbol	Condition	Min.	Тур.	Max.	Unit
Operating Temperature Range	Тор	Absolute Max	-20	•	+70	°C
Storage Temperature Range	Tst	Absolute Max	-30	-	+80	Oo
Supply Voltage	VDD		4.7	5.0	5.5	V
Supply Current	IDD	Ta=25°C,VDD=5.0V	-	1.0	1.5	mA
Supply for LCD (contrast)	VDD-Vo	Ta=25 °C	-	4.7	-	V
"H" Level input	Vih		0.8*VDD	-	VDD	V
"L" Level input	VIL		-0.3	-	0.2*VDD	V
"H" Level output	Voн		VDD-0.6	-	-	V
"L" Level output	Vol		-	ı	GND+0.6	V
Backlight Supply Voltage	VLED		-	3.0	-	V
Backlight Supply Current	ILED	VLED=3.0V		15	20	mA

Optical Characteristics

Item	Symbol	Condition	Min.	Тур.	Max.	Unit
Viewing Angle - Vertical	AV	Cr ≥ 2	-60	-	+35	0
Viewing Angle - Horizontal	AH	Cr ≥ 2	-40	-	+40	0
Contrast Ratio	Cr		-	6	-	-
Response Time (rise)	Tr	-	-	150	250	ms
Response Time (fall)	Tr	-	-	150	250	ms

Controller Information

Built-in NT7605. Download specification at http://www.newhavendisplay.com/app_notes/NT7605.pdf

DDRAM address location:

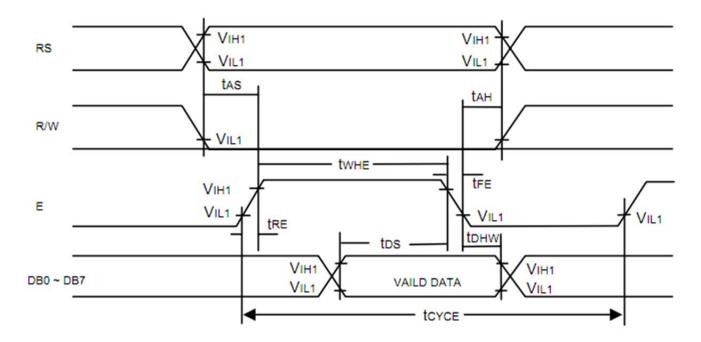
1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16
00	01	02	03	04	05	06	07	08	09	0A	0B	0C	0D	0E	0F
40	41	42	43	44	45	46	47	48	49	4A	4B	4C	4D	4E	4F

Table of Commands

Instruction					Co	ode					Function	Execution time (max)	
	RS	RW	DB7	DB6	DB5	DB4	DB3	DB2	DB1	DB0		(f _{osc} = 250KHz)	
Display Clear	0	0	0	0	0	0	0	0	0	1	Clear entire display area, Restore display from shift, and load address counter with DD RAM address 00H.	1.64ms	
Display/ Cursor Home	0	0	0	0	0	0	0	0	1	•	Restore display from shift and load address counter with DD RAM address 00H.	1.64ms	
Entry Mode Set	0	0	0	0	0 0 0 1 I/D S				I/D	s	Specify direction of cursor movement and display shift mode. This operation takes place after each data transfer (read/write).	40μs	
Display ON/OFF	0	0	0	0	0	0	1	D	С	В	Specify activation of display (D) cursor (C) and blinking of character at cursor position (B).	40µs	
Display/ Cursor Shift	0	0	0	0	0	1	S/C	R/L			Shift display or move cursor.	40μs	
Function Set	0	0	0	0	1	DL	N	F		•	Set interface data length (DL), number of display line (N), and character font (F).	40μs	
RAM Address Set	0	0	0	1			AC	CG			Load the address counter with a CG RAM address. Subsequent data access is for CG RAM data.		
DD RAM Address Set	0	0	1				ADD				Load the address counter with a DD RAM address. Subsequent data access is for DD RAM data.	40μs	
Busy Flag/ Address Counter Read	0	1	BF				AC				Read Busy Flag (BF) and contents of Address Counter (AC).	1μs	
CG RAM/ DD RAM Data Write	1	0				Write	data				Write data to CG RAM or DD RAM.	40μs	
CG RAM/ DD RAM Data Read	1	1				Read	data				Read data from CG RAM or DD RAM.	40μs	
	S : D : C : B : S/C : R/L : DL : N : F : BF :	= 1 : Dis = 1 : Dis = 1 : Cu = 1 : Cu = 1 : Sh = 1 : Sh = 1 : Du = 1 : 5x = 1 : Int	rsor Blir nift Disp nift Right Bit ral Line 10 dots ernal Op	nift On n splay Or nk On lay	ı	S/C R/ DL N F	DD RAM: Display Data RAM CG RAM: Character Generator RAM ACG: Character Generator RAM Address ADD: Display Data RAM Address AC: Address Counter						

Timing Characteristics

Write Operation



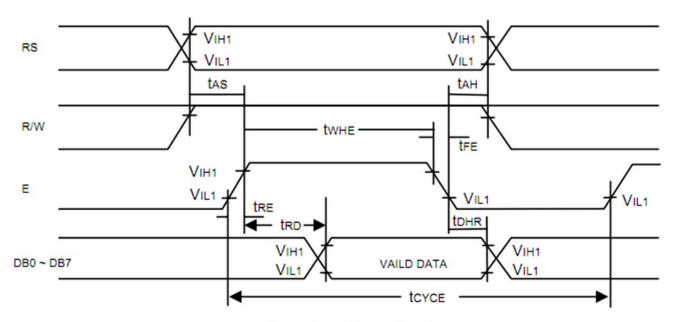
Bus Write Operation Sequence (Writing data from MPU to NT7605)

Write Cycle (VDD = 5.0V, GND = 0V, TA = 25°C)

Symbol	Parameter	Min.	Тур.	Max.	Unit	Conditions	
tcyce	Enable Cycle Time	500	-	-	ns	Figure 2	
twhe	Enable "H" Level Pulse Width	300	-	-	ns	Figure 2	
tre, tre	Enable Rise/Fall Time	-	-	25	ns	Figure 2	
tas	RS, R/W Setup Time	60 ¹	-	-	ns	Figure 2	
		100 ²					
tan	RS, R/W Address Hold Time	10	-	-	ns	Figure 2	
tos	Data Output Delay	100	-	-	ns	Figure 2	
t DHW	Data Hold Time	10	-	-	ns	Figure 2	

Notes: 1: 8-bit operation mode 2: 4-bit operation mode

Read Operation



Bus Read Operation Sequence (Reading out data from NT7605 to MPU)

Read Cycle (VDD = 5.0V, GND = 0V, TA = 25°C)

Symbol	Parameter	Min.	Тур.	Max.	Unit	Conditions
toyce	Enable Cycle Time	500	-	-	ns	Figure 1
twhe	Enable "H" Level Pulse Width	300	-	-	ns	Figure 1
tre, tre	Enable Rise/Fall Time	-	-	25	ns	Figure 1
tas	RS, R/W Setup Time	60 ¹	-	-	ns	Figure 1
		100 ²				
tан	RS, R/W Address Hold Time	10	-	-	ns	Figure 1
tRD	Read Data Output Delay	-	-	190	ns	Figure 1
tohr	Read Data Hold Time	20	-	-	ns	Figure 1

Notes: 1: 8-bit operation mode 2: 4-bit operation mode

Built-in Font Table

Lower Bits	0000	0001	0010	0011	0100	0101	0110	0111	1000	1001	1010	1011	1100	1101	1110	1111
xxxx0000	CG RAM (1)			0	a	P	`	P					9	Ξ.	α	þ
xxxx0001	(2)		!	1	A	Q	a	4			0	7	Ŧ	4	ä	q
xxxx0010	(3)		11	2	В	R	b	r			Г	1	ij	×	F	0
xxxx0011	(4)		#	3	C	S	C	s			L	Ċ	Ť	ŧ	Ø	60
xxxx0100	(5)		\$	4	D	T	d	ţ.			ν.	I	ŀ	þ	Н	υ
xxxx0101	(6)		%	5	E	U	e	u			=	7	t	1	G	ü
xxxx0110	(7)		&	6	F	Ų	f	V			7	Ħ	_	3	ρ	Σ
xxxx0111	(8)		7	7	G	W	g	W			7	†	Z	Þ	9	π
xxxx1000	(1)		(8	H	X	h	×			4	7	ネ	IJ	Л	\overline{x}
xxxx1001	(2))	9	Ι	Υ	i	9			Ċ	ጛ	J	լև	-1	y
xxxx1010	(3)		*	=	J	Z	j	Z			I		ń	V	j	¥
xxxx1011	(4)		+	;	K		k	{			7	#	L		×	ħ
xxxx1100	(5)		,	<	L	¥	1				t	Ð	J	7	4	Ħ
xxxx1101	(6)			=	M]	M	}			ュ	Z	ኅ	٥	Ł	÷
xxxx1110	(7)			>	И	^	n	÷			3	t	#	**	ħ	
xxxx1111	(8)		/	?	0		0	÷			·y	y	7		Ö	

Example Initialization Program

'INIT	
A = &H30 Call Writecom	'wake up
Waitms 100	·
Call Writecom Waitms 10	'wake up
Call Writecom	'wake up
Waitms 10 A = &H38	'function set
Call Writecom A = &H10	'shift display-no
Call Writecom	'shift display=no
A = &H0C Call Writecom	'display on
A = &H06	'entry mode set
Call Writecom	
Sub Writecom	
P1 = A Reset P3.0	'instruction
Reset P3.7	'RW
Waitms 1 Set P3.4	Έ
Waitms 1 Reset P3.4	'E
End Sub	-
'Sub Writedata	
P1 = A	
Set P3.0 Reset P3.7	'data 'RW
Waitms 1	
Set P3.4 Waitms 1	Έ
Reset P3.4	'E
End Sub	

Quality Information

Test Item	Content of Test	Test Condition	Note
High Temperature storage	Endurance test applying the high storage temperature for a long time.	+80°C , 48hrs	2
Low Temperature storage	Endurance test applying the low storage temperature for a long time.	-30°C , 48hrs	1,2
High Temperature Operation	Endurance test applying the electric stress (voltage & current) and the high thermal stress for a long time.	+70°C , 48hrs	2
Low Temperature Operation	Endurance test applying the electric stress (voltage & current) and the low thermal stress for a long time.	-20°C , 48hrs	1,2
High Temperature / Humidity Operation	Endurance test applying the electric stress (voltage & current) and the high thermal with high humidity stress for a long time.	+40°C, 90% RH, 48hrs	1,2
Thermal Shock resistance	Endurance test applying the electric stress (voltage & current) during a cycle of low and high thermal stress.	0°C,30min -> 25°C,5min -> 50°C,30min = 1 cycle 10 cycles	
Vibration test	Endurance test applying vibration to simulate transportation and use.	10-55Hz , 15mm amplitude. 60 sec in each of 3 directions X,Y,Z For 15 minutes	3
Static electricity test	Endurance test applying electric static discharge.	VS=800V, RS=1.5k Ω , CS=100pF One time	

Note 1: No condensation to be observed.

Note 2: Conducted after 4 hours of storage at 25°C, 0%RH.

Note 3: Test performed on product itself, not inside a container.

Precautions for using LCDs/LCMs

See Precautions at www.newhavendisplay.com/specs/precautions.pdf

Warranty Information and Terms & Conditions

http://www.newhavendisplay.com/index.php?main_page=terms